

60 V, 6 A PNP high power bipolar transistor 9 December 2014

Product data sheet

1. General description

PNP high power bipolar transistor in a SOT669 (LFPAK56) Surface-Mounted Device (SMD) power plastic package.

NPN complement: PHPT60606NY.

2. Features and benefits

- High thermal power dissipation capability
- Suitable for high temperature applications up to 175 °C
- Reduced Printed-Circuit Board (PCB) requirements comparing to transistors in DPAK
 - High energy efficiency due to less heat generation
 - AEC-Q101 qualified

3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- Backlighting applications
- Motor drive
- Relay replacement

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-60	V
I _C	collector current			-	-	-6	А
I _{CM}	peak collector current	$t_p \le 1 ms; pulsed$		-	-	-12	А
R _{CEsat}	collector-emitter saturation resistance	I_{C} = -6 A; I_{B} = -600 mA; pulsed; $t_{p} \le 300$ μs; δ ≤ 0.02; T_{amb} = 25 °C		-	66	88	mΩ

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter	mb	С
2	E	emitter		в
3	E	emitter	d	1×
4	В	base	មុច្ចុថ្	sym132
mb	С	collector	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PHPT60606PY	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PHPT60606PY	0606PAB

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

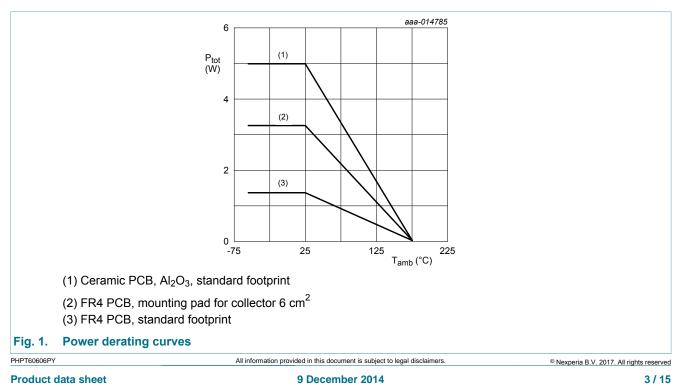
Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CBO}	collector-base voltage	open emitter		-	-60	V
V _{CEO}	collector-emitter voltage	open base		-	-60	V
V _{EBO}	emitter-base voltage	open collector		-	-8	V
I _C	collector current			-	-6	А
I _{CM}	peak collector current	$t_p \le 1 \text{ ms}; \text{ pulsed}$		-	-12	А
I _B	base current			-	-800	mA
I _{BM}	peak base current	$t_p \le 1 ms$; pulsed		-	-1.2	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1.35	W
			[2]	-	3.25	W
			[3]	-	5	W
			[4]	-	25	W
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

[4] Power dissipation from junction to mounting base.

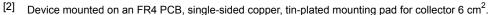


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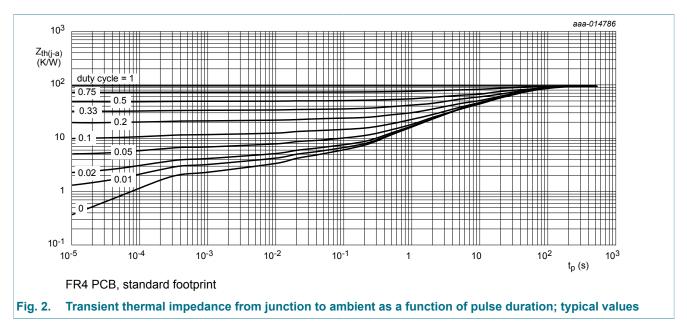
9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient		in free air	[1]	-	-	111	K/W
	-		[2]	-	-	46	K/W
	ambient		[3]	-	-	30	K/W
R _{th(j-mb)}	thermal resistance from junction to mounting base			-	-	6	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



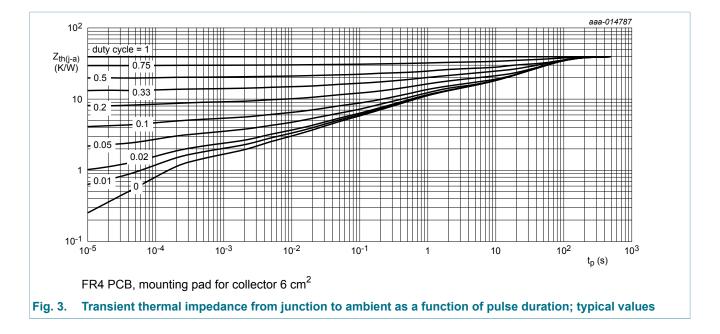




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10. Characteristics

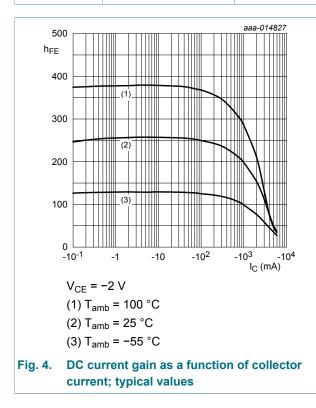
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -48 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V_{CB} = -48 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = -48 V; V_{BE} = 0 V; T_{amb} = 25 °C	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = -8 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE} [DC current gain	V_{CE} = -2 V; I _C = -500 mA; T _{amb} = 25 °C	120	200	-	
		$\begin{split} &V_{CE}\texttt{=-2 V; } I_{C}\texttt{=-1 A; } t_{p}\texttt{\leq}300 \ \mu\texttt{s};} \\ &\delta \texttt{\leq} 0.02; \ T_{amb}\texttt{=}25 \ ^{\circ}C; \ pulsed \end{split}$	110	180	-	
		$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -3 \text{ A}; \text{ t}_{p} \le 300 \mu\text{s};$ $\overline{\delta} \le 0.02; \text{ T}_{amb} = 25 \text{ °C}; \text{ pulsed}$	60	100	-	
		V_{CE} = -2 V; I _C = -6 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C	20	30	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -1 A; I_B = -50 mA; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-75	-110	mV
		I_C = -3 A; I_B = -300 mA; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C; pulsed	-	-155	-230	mV
		I_{C} = -6 A; I_{B} = -600 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02; T_{amb} = 25 °C	-	-395	-525	mV
R _{CEsat}	collector-emitter saturation resistance	I_{C} = -6 A; I_{B} = -600 mA; pulsed; $t_{p} \le 300 \ \mu$ s; $\overline{\delta} \le 0.02$; T_{amb} = 25 °C	-	66	88	mΩ

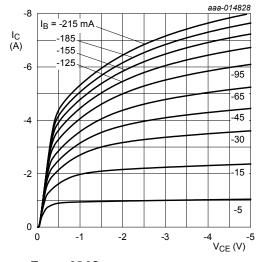
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{BEsat} base-emitter satu voltage		I _C = -1 A; I _B = -50 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-0.85	-0.95	V
		I_{C} = -3 A; I_{B} = -300 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-1	-1.1	V
		I _C = -6 A; I _B = -600 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-1.1	-1.3	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I _C = -0.5 A; T _{amb} = 25 °C	-	-0.75	-0.85	V
t _d	delay time	V _{CC} = -12.5 V; I _C = -3 A; I _{Bon} = -150 mA; I _{Boff} = 150 mA;	-	15	-	ns
t _r	rise time		-	110	-	ns
t _{on}	turn-on time	T _{amb} = 25 °C	-	125	-	ns
ts	storage time		-	185	-	ns
t _f	fall time		-	70	-	ns
t _{off}	turn-off time		-	255	-	ns
f _T	transition frequency	V _{CE} = -10 V; I _C = -500 mA; f = 100 MHz; T _{amb} = 25 °C	-	110	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	57	-	pF





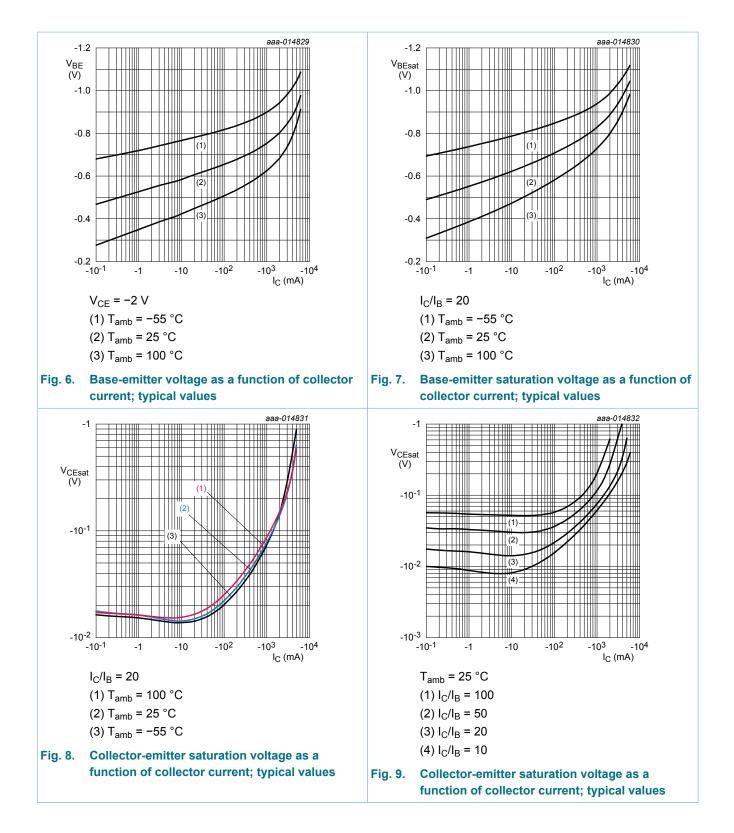




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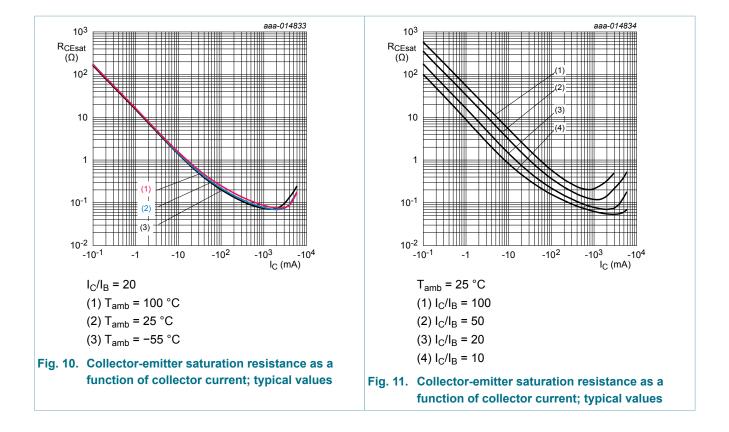
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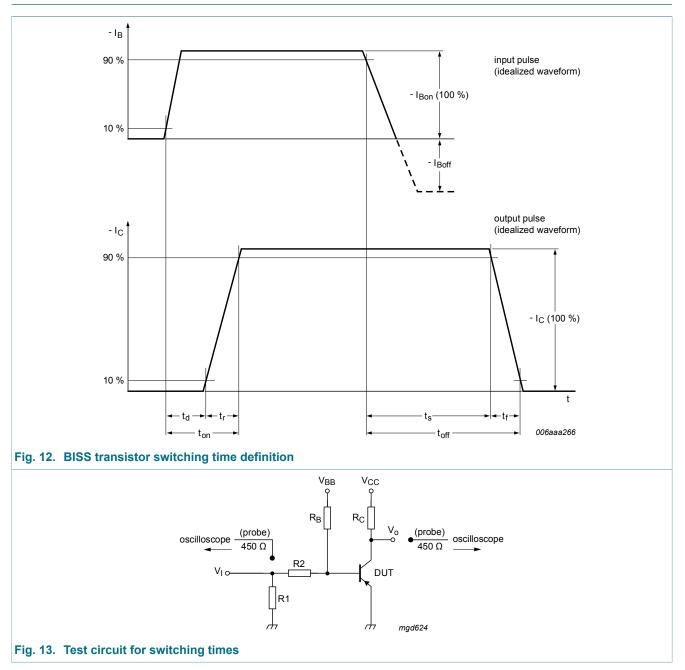
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11. Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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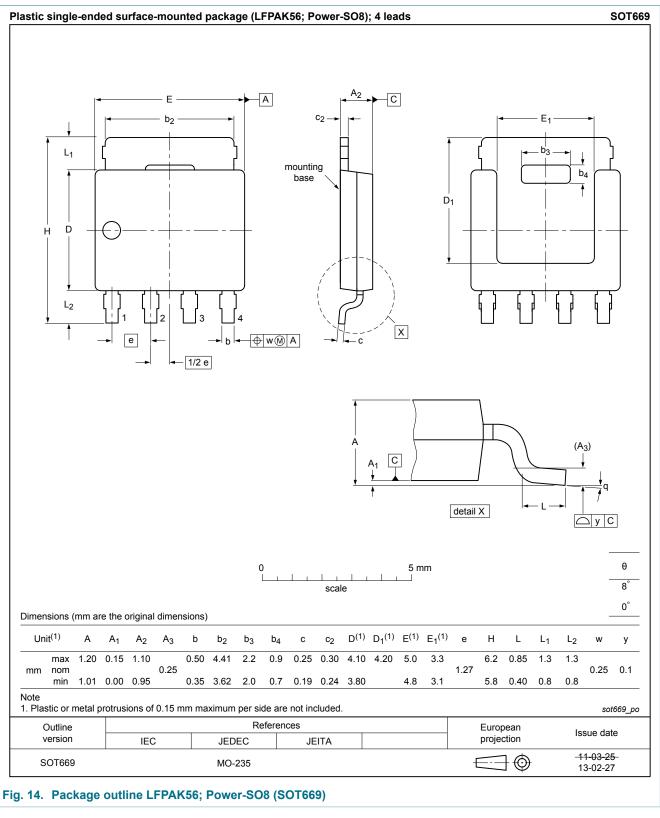
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12. Package outline



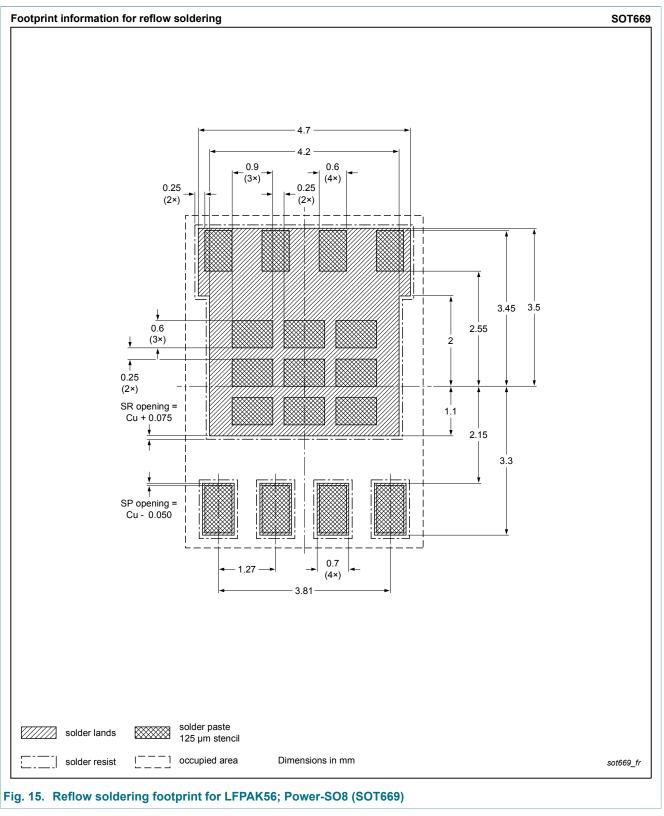
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13. Soldering



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14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PHPT60606PY v.1	20141209	Product data sheet	-	-

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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